	CN Number: 20210203000.2A PCN Date: Apr 15, 2021								
Comparison of RFAB as an additional Fab site option for select ABCD6 devices									
Customer C	Contact:	PCN N	lanager	Dept: Quality Serv				ervices	
Proposed 1			, 2021		ted Samp	le D	ample re	ided at	
Change Typ									
Assemb	ly Site		Assembly Pro				mbly Mat		
Design			Electrical Spe					ecification	
Test Sit				ping/Labeling	<u> </u>		Process		
	Bump Site		Nafer Bump				<u>r Bump P</u>		
🛛 🛛 Wafer F	ab Sile		Nafer Fab Ma Part number (wale	r Fab Pro	cess	
				Details					
Description	of Chang	21	PCN	Details					
notification. pelow. The	The new de expected fin added devi	nce the <u>additia</u> vices are high rst shipment d ces only. The	lighted in ye ate for the n	llow and bold ew devices wil	ed in the II be 180 d	product days fro	affected	section otice for	
-	Curren	t Fab Site		Additional Fab Site					
Current Fab Site	Process	Passivation	Wafer Diameter	Additional Fab Site	Process	Pass	ivation	Wafer Diamete	
MAINEFAB	ABCD6	SiN	200 mm	RFAB	ABCD6	S	SiON	300 mm	
Reason for Continuity o	Change: f Supply	d in the Qual							
Reason for Continuity of Anticipated	Change: f Supply	d in the Qual			ability (po	ositive	/ negat	ive):	
Reason for Continuity or Anticipated None	Change: f Supply l impact or		unction, Qu	ality or Relia		ositive	/ negat	ive):	
Reason for Continuity o Anticipated None Changes to	Change: f Supply l impact or	n Form, Fit, F	unction, Qu	ality or Relia		ositive	/ negat	ive):	
Reason for Continuity or Anticipated None Changes to Current:	Change: f Supply l impact or product io	n Form, Fit, F dentification	unction, Qu resulting fr	ality or Relia					
Reason for Continuity of Anticipated None Changes to Current: Current Chi	Change: f Supply l impact or product id ip Site Ch	Form, Fit, F Jentification ip Site Origin	unction, Qu resulting fr	ality or Relia	untry Code		Chip S	Site City	
Reason for Continuity or Anticipated None Changes to Changes to Current: Current Chi MAINEF New Fab Si	Change: f Supply l impact or product id p Site Ch AB te:	n Form, Fit, F dentification	unction, Qu resulting fr	ality or Relia			Chip South	Site City Portland	
Reason for Continuity of Anticipated None Changes to Changes to Current: Current Chi MAINEF	Change: f Supply l impact or product id p Site Ch AB te:	Form, Fit, F Jentification ip Site Origin	Function, Qu resulting fr Code (20L)	ality or Relia	intry Code	e (21L)	Chip South	Site City	
Reason for Continuity or Anticipated None Changes to Current: Current Chi MAINEF New Fab Si	Change: f Supply I impact or product id ip Site Ch AB te: Site Ch	Form, Fit, F dentification ip Site Origin CUA	Function, Qu resulting fr Code (20L)	om this PCN: Chip Site Cou	intry Code	e (21L)	Chip South	Site City Portland	

Texas Instruments Incorporated

Product Affected:								
INA240A1EDRQ1	INA240A2QDRQ1	INA240A4EDRQ1	LM25141QRGETQ1					
INA240A1QDRQ1	INA240A3EDRQ1	INA240A4QDRQ1	LM5141QRGERQ1					
INA240A2EDRQ1	INA240A3QDRQ1	LM25141QRGERQ1	LM5141QRGETQ1					

Automotive New Product Qualification Summary

(As per AEC-Q100 and JEDEC Guidelines)

Approved 25-January-2021

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

	Туре	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name / Condition	Duration	Qual Device: LM5141QRGERQ1
Te	st Group A	A – Acc	elerated Environment Stress Test	S				
	PC	A1	JEDEC J-STD-020 JESD22- A113	3	231	Automotive Preconditioning	Level 2-260C	Pass
	uHAST	A3	JEDEC JESD22-A102	3	77	Unbiased HAST, 110C/85%RH	264 Hours	3/231/0
	THB		JEDEC JESD22-A101	3	77	Biased Temperature and Humidity, 85C/85%RH	1000 Hours	3/231/6 (Note 1)
	тс	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle, -65/150C	500 Cycles	3/231/0
	PTC	A5	JEDEC JESD22-A105	1	45	Power Temperature Cycle	1000 Cycles	N/A
	HTSL	A6	JEDEC JESD22-A103	1	45	High Temp. Storage Life, 175C	500 Hours	3/231/0
Te	st Group E	3 – Acc	elerated Lifetime Simulation Tests	3			1	
	HTOL	B1	JEDEC JESD22-A108	3	77	Life Test. 125C	1000 Hours	3/231/0
	ELFR	B2	AEC Q100-008	3	800	Early Life Failure Rate, 125C	48 Hours	3/2400/0
	EDR	B3	AEC Q100-005	3	77	NVM Endurance, Data Retention, and Operational Life	10000 Cycles	3/231/0
Те	st Group (C – Pac	kage Assembly Integrity Tests					
	WBS	C1	AEC Q100-001	1	30	Bond Shear (Cpk>1.67)	Wires	3/90/0
	WBP	C2	MIL-STD883 Method 2011	1	30	Bond Pull (Cpk>1.67)	Wires	3/90/0
	PD	C4	JEDEC JESD22-B100 and B108	3	10	Physical Dimensions (Cpk>1.67)	30 units	3/90/0
	SBS	C5	AEC Q100-010	3	50	Solder Ball Shear (Cpk>1.67)	Solder Balls	N/A
Te	st Group [) – Die	Fabrication Reliability Tests					
	EM	D1	JESD61	-	-	Electromigration		Completed Per Process Technology Requirements
	TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown		Completed Per Process Technology Requirements
	HCI	D3	JESD60 & 28	-	-	Hot Injection Carrier		Completed Per Process Technology Requirements
	NBTI	D4	-	-	-	Negative Bias Temperature Instability		Completed Per Process Technology Requirements
	SM	D5	-	-	-	Stress Migration		Completed Per Process Technology Requirements

Те	Test Group E – Electrical Verification Tests										
	HBM	E2	AEC Q100-002	1	3	ESD - HBM	2000 V	1/3/0			
	CDM	E3	AEC Q100-011	1	3	ESD - CDM	750 V	1/3/0			
	LU	E4	AEC Q100-004	1	6	Latch-up	+/100mA, 125C	1/6/0			
	ED	E5	AEC Q100-005	3	30	Electrical Distribution	Cpk > 1.67	3/30/0			
QB	2BS; Qual By Similarity										

- Qual Device LM5141QRGERQ1 is gualified at LEVEL2-260C

A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40°C to +150°C Grade 1 (or Q): -40°C to +125°C Grade 2 (or T): -40°C to +105°C attributed these to board issues and were discounted as not related Grade 3 (or I): -40°C to +85°C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU Room: AC/uHAST

Green/Pb-free Status:

Qualified Pb-Free (SMT) and Green

Note 1: 6 fails across 3 lots (as well as 6 fails on control material) were attributed to electrically induced physical damage. Extensive FA and 8D (attached to eQDB) attributed these to board issues and were discounted as not related to the fab change.

Revision A Qual Memo

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Approved 25-Mar-2021

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	\$\$/Lot	Test Name / Condition	Duration	Qual Device: INA240A1EDQ1	Qual Device: INA240A2EDQ1	Qual Device: INA240A3EDQ1	Qual Device: INA240A4EDQ1
		Test Group A –	Accele	rated Env	ironment Stress Tests					
PC	A1	JEDEC J- STD-020 JESD22-A113	3	77	Automotive Preconditioning	Level 2-260C	Pass	Pass	Pass	
HAST	A2	JEDEC JESD22-A110	3	77	Biased HAST, 130C/85%RH	96 Hrs/+130C/85% RH	1/77/0	1/77/0	1/77/0	-
UHAST	A3	JEDEC JESD22- A <u>102,A</u> 118 or A101	3	77	Unbiased HAST 130C/85%RH	96 Hrs/130C/85% RH	1/77/0	1/77/0	1/77/0	-
TC	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle, - 65/150C	1000 Cycs/- 65C/+150C	1/77/0	1/77/0	1/77/0	-
TC	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle, - 65/150C	1820 Cycs/- 65C/+150C	1/77/0	1/77/0	1/77/0	-
тс	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle, - 65/150C	2000 Cycs/- 65C/+150C	1/77/0	1/73/0	1/73/0	-
TC-WBP	A4	MIL-STD883 Method 2011	1	60	Auto Post TC Bond Pull	30 ball bonds, min. 5 units	1/5/0	-	-	-
PTC	A5	JEDEC JESD22-A105	1	45	Power Temperature Cycle	1000 Cycles	N/A	N/A	N/A	N/A
HTSL	A6	JEDEC JESD22-A103	1	45	High Temp Storage Bake 175C	1000 Hrs/175C	1/45/0	-	-	-

Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: INA240A1EDQ1	Qual Device: INA240A2EDQ1	Qual Device: INA240A3EDQ1	Qual Device: INA240A4EDQ1
		Test Group B –	Accele	rated Life	time Simulation Tests					
HTOL	В1	JEDEC JESD22-A108	3	77	HTOL	1000 Hrs/150C	1/77/0	1/77/0	1/77/0	-
ELFR	B2	ACE Q100- 008	3	800	ELFR	48 Hrs/150C	1/800/0	1/800/0	1/800/0	-
EDR	В3	AEC Q100- 005	3	77	NVM Endurance, Data Retention, and Operational Life	-	N/A	N/A	N/A	N/A
		Test Group C	: – Pack	kage Asse	mbly Integrity Tests					
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear (Cpk>1.67)	-	1/3/0/0*	-	-	-
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull (Cpk>1.67)	-	1/30/0*	-	-	-
SD	СЗ	JEDEC JESD22-B102	1	15	Surface Mount Solderability >95% Lead Coverage	Pb and Pb-free	1/15/0* 1/15/0*	-	-	-
PD	C4	JEDEC JESD22-B100 and B108	3	10	Physical Dimensions (Cpk>1.67)	-	1/10/0*	-	1/10/0*	1/10/0*
		Test Group	D – Die	Fabricati	on Reliability Tests					
EM	D1	JESD61	-	-	Electromigration	-	Completed Per Process Technology Requirements	Completed Per Process Technology Reguirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
нсі	D3	JESD60 & 28	-	-	Hot Injection Carrier	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
		Test Grou	ip E – E	lectrical \	erification Tests					
нвм	E2	AEC Q100- 002	1	3	ESD - HBM - Q100	2500 V	1/3/0	1/3/0	-	-

Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: INA240A1EDQ1	Qual Device: INA240A2EDQ1	Qual Device: INA240A3EDQ1	Qual Device: INA240A4EDQ1
нвм	E2	AEC Q100- 002	1	3	ESD - HBM - Q100	4000 V	-	-	1/3/0	-
CDM	E3	AEC Q100- 011	1	3	ESD - CDM - Q100	1500 V	1/3/0	1/3/0	1/3/0	-
LU	E4	AEC Q100- 004	1	6	Latch-up	150C	1/6/0	1/6/0	1/6/0	-
ED	E5	AEC Q100- 009	3	30	Auto Electrical Distributions	Cpk>1.67 Room, hot, and cold test	1/30/0	1/30/0	1/30/0	1/30/0

- QBS: Qual By Similarity

Qual Device INA240A4EDQ1 is qualified at LEVEL2-260C
 Qual Device INA240A3EDQ1 is qualified at LEVEL2-260C
 Qual Device INA240A1EDQ1 is qualified at LEVEL2-260C

- Qual Device INA240A2EDQ1 is qualified at LEVEL2-260C

A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable. *From 20160922-119344

 Ambient Operating Temperature by Automotive Grade Level:
 Grade 0 (or E): -40°C to +150°C
 Grade 1 (or Q): -40°C to +125°C
 Grade 2 (or T): -40°C to +105°C
 Grade 2 (or T): -40°C to +100°C
 Grade 2 (or T): -40°C to +100°C
Grade 3 (or I): -40°C to +85°C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED Room/Hot/Cold: HTOL, TC / PTC, HTSL, ELFR, ESD & LU Room: AC/uHAST

Green/Pb-free Status: Qualified Pb-Free (SMT) and Green

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